



Electrically isolated base plate
Industrial standard package
Simplified mechanical design, rapid assembly
Pressure contact

Double Diode Module
For Phase Control
MDx-400-18-C1

| | | | | | | | | |
|---------------------------------|------------|------|------|-----------|------|---------------|------|------|
| Average forward current | | | | I_{FAV} | | 400 A | | |
| Repetitive peak reverse voltage | | | | V_{RRM} | | 1000...1800 V | | |
| V_{RRM}, V | 1000 | 1100 | 1200 | 1300 | 1400 | 1500 | 1600 | 1800 |
| Voltage code | 10 | 11 | 12 | 13 | 14 | 15 | 16 | 18 |
| $T_j, ^\circ C$ | -40...+150 | | | | | | | |

| MD3 | MD4 | MD5 |
|-----|-----|-----|
| | | |
| | | |
| | | |
| | | |

All dimensions in millimeters (inches)

MAXIMUM ALLOWABLE RATINGS

| Symbols and parameters | | Units | Values | Test conditions |
|------------------------|---|-------------------|---------------------|---|
| ON-STATE | | | | |
| I_{FAV} | Maximum allowable average forward current | A | 400 484 | $T_c = 110\text{ }^\circ\text{C}$; $T_c = 100\text{ }^\circ\text{C}$; 180° half-sine wave; 50 Hz |
| I_{FRMS} | RMS forward current | A | 628 | $T_c = 110\text{ }^\circ\text{C}$; 180° half-sine wave; 50 Hz |
| I_{FSM} | Surge forward current | kA | 12.0 14.0 | $T_j = T_{j\text{ max}}$ $T_j = 25\text{ }^\circ\text{C}$ 180° half-sine wave; $t_p = 10\text{ ms}$; single pulse; $V_R = 0\text{ V}$ |
| | | | 13.0 15.0 | $T_j = T_{j\text{ max}}$ $T_j = 25\text{ }^\circ\text{C}$ 180° half-sine wave; $t_p = 8.3\text{ ms}$; single pulse; $V_R = 0\text{ V}$ |
| I^2t | Safety factor | $A^2s \cdot 10^3$ | 720 980 | $T_j = T_{j\text{ max}}$ $T_j = 25\text{ }^\circ\text{C}$ 180° half-sine wave; $t_p = 10\text{ ms}$; single pulse; $V_R = 0\text{ V}$ |
| | | | 700 930 | $T_j = T_{j\text{ max}}$ $T_j = 25\text{ }^\circ\text{C}$ 180° half-sine wave; $t_p = 8.3\text{ ms}$; single pulse; $V_R = 0\text{ V}$ |
| BLOCKING | | | | |
| V_{RRM} | Repetitive peak reverse voltages | V | 1000...1800 | $T_{j\text{ min}} < T_j < T_{j\text{ max}}$; 180° half-sine wave; 50 Hz |
| V_{RSM} | Non-repetitive peak reverse voltages | V | 1100...1900 | $T_{j\text{ min}} < T_j < T_{j\text{ max}}$; 180° half-sine wave; single pulse |
| V_R | Reverse continuous voltages | V | $0.6 \cdot V_{RRM}$ | $T_j = T_{j\text{ max}}$ |
| THERMAL | | | | |
| T_{stg} | Storage temperature | $^\circ\text{C}$ | -40...+50 | |
| T_j | Operating junction temperature | $^\circ\text{C}$ | -40...+150 | |
| $T_{c\text{ op}}$ | Operating temperature | $^\circ\text{C}$ | -40...+125 | |
| MECHANICAL | | | | |
| a | Acceleration under vibration | m/s^2 | 50 | |

CHARACTERISTICS

| Symbols and parameters | | Units | Values | Conditions |
|------------------------|--------------------------------------|---------------------------|------------|---|
| ON-STATE | | | | |
| V_{FM} | Peak forward voltage, max | V | 1.20 | $T_j = 25\text{ }^\circ\text{C}$; $I_{FM} = 785\text{ A}$ |
| $V_{F(TO)}$ | Forward threshold voltage, max | V | 0.917 | $T_j = T_{j\text{ max}}$; |
| r_T | Forward slope resistance, max | $\text{m}\Omega$ | 0.313 | $0.5 \pi I_{FAV} < I_T < 1.5 \pi I_{FAV}$ |
| BLOCKING | | | | |
| I_{RRM} | Repetitive peak reverse current, max | mA | 30 2.50 | $T_j = T_{j\text{ max}}$ $T_j = 25\text{ }^\circ\text{C}$ $V_R = V_{RRM}$ |
| SWITCHING | | | | |
| Q_r | Recovered charge, max | μC | 1300 | $T_j = T_{j\text{ max}}$; $I_{FM} = I_{FAV}$; $di_R/dt = -10\text{ A}/\mu\text{s}$; $V_R = 100\text{ V}$ |
| t_{rr} | Reverse recovery time, max | μs | 20 | |
| I_{rr} | Reverse recovery current, max | A | 130 | |
| THERMAL | | | | |
| R_{thjc} | Thermal resistance, junction to case | | | 180° half-sine wave, 50 Hz |
| | per module | $^\circ\text{C}/\text{W}$ | 0.0400 | |
| | per arm | $^\circ\text{C}/\text{W}$ | 0.0800 | |
| R_{thch} | Thermal resistance, case to heatsink | | | |
| | per module | $^\circ\text{C}/\text{W}$ | 0.0200 | |
| | per arm | $^\circ\text{C}/\text{W}$ | 0.0400 | |

| INSULATION | | | | | |
|-------------------|---|----|------|--------------------------|----------|
| V _{ISOL} | Insulation test voltage | kV | 3.00 | Sine wave, 50 Hz; RMS | t=60 sec |
| | | | 3.60 | | t=1 sec |
| MECHANICAL | | | | | |
| M ₁ | Mounting torque (M6) ¹⁾ | Nm | 6.00 | Tolerance ± 15% | |
| M ₂ | Terminal connection torque (M8) ¹⁾ | Nm | 9.00 | Tolerance ± 15% | |
| m | Weight, max | g | 860 | | |

| PART NUMBERING GUIDE | | | | | | NOTES | | | | | |
|---|---|---|-----|---|----|-------|----|---|---|--|---|
| MD | 3 | - | 400 | - | 18 | - | C1 | - | N | | ¹⁾ The screws must be lubricated |
| 1 | 2 | | 3 | | 4 | | 5 | | 6 | | |
| 1. MD - Rectifier Diode 2. Circuit Schematic 3. Average Forward Current, A 4. Voltage Code 5. Package Type (M.C1) 6. Ambient Conditions: N – Normal | | | | | | | | | | | |

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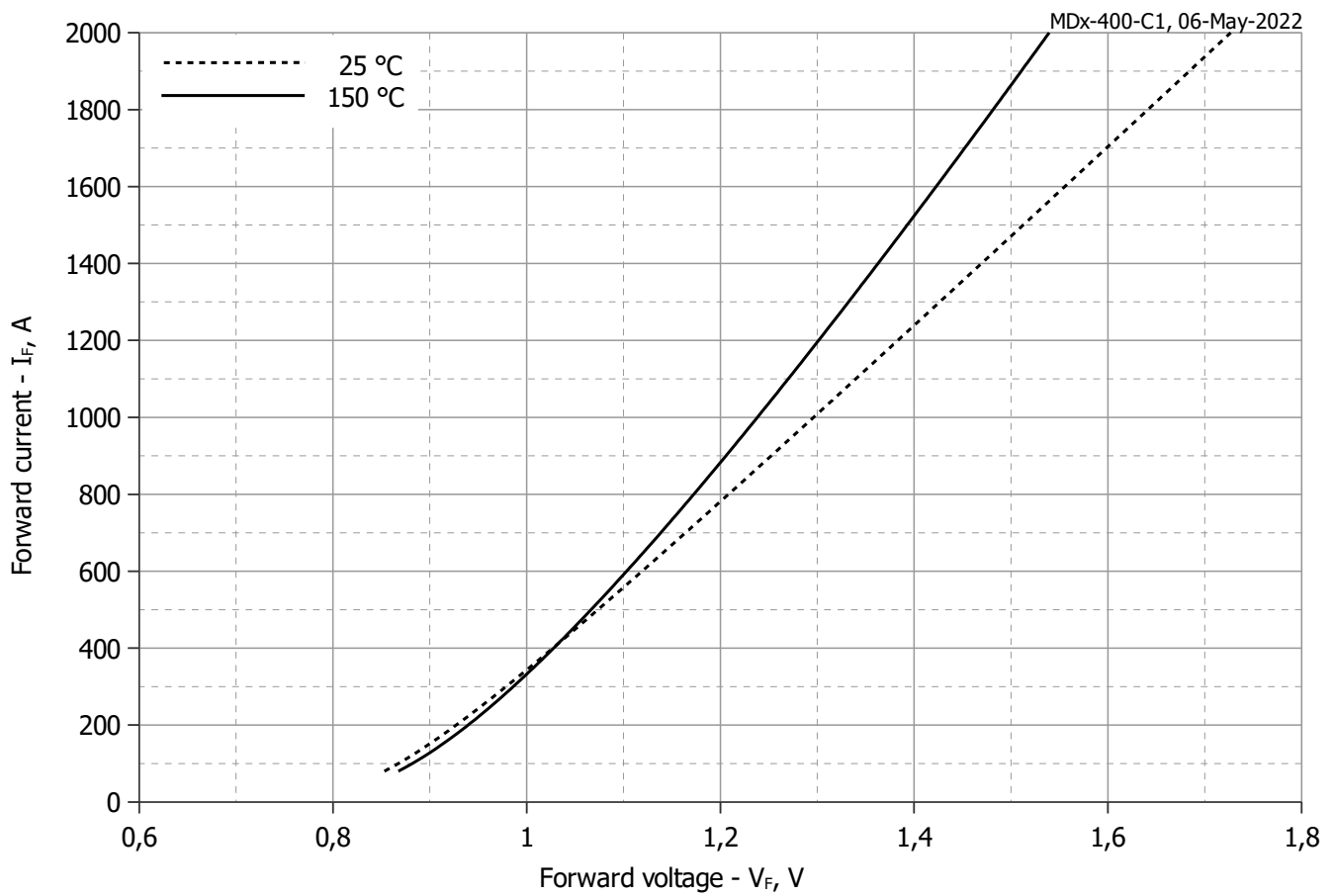


Fig 1 – Forward characteristics of Limit device

Analytical function for Forward characteristic:

$$V_F = A + B \cdot i_F + C \cdot \ln(i_F + 1) + D \cdot \sqrt{i_F}$$

| | Coefficients for max curves | |
|----------|-----------------------------|-------------------------|
| | $T_j = 25^\circ\text{C}$ | $T_j = T_{j\text{max}}$ |
| A | 0.68139440 | 0.71130813 |
| B | 0.00042933 | 0.00022039 |
| C | 0.03479867 | 0.02124824 |
| D | -0.00173841 | 0.00504965 |

Forward characteristic model (see Fig. 1).

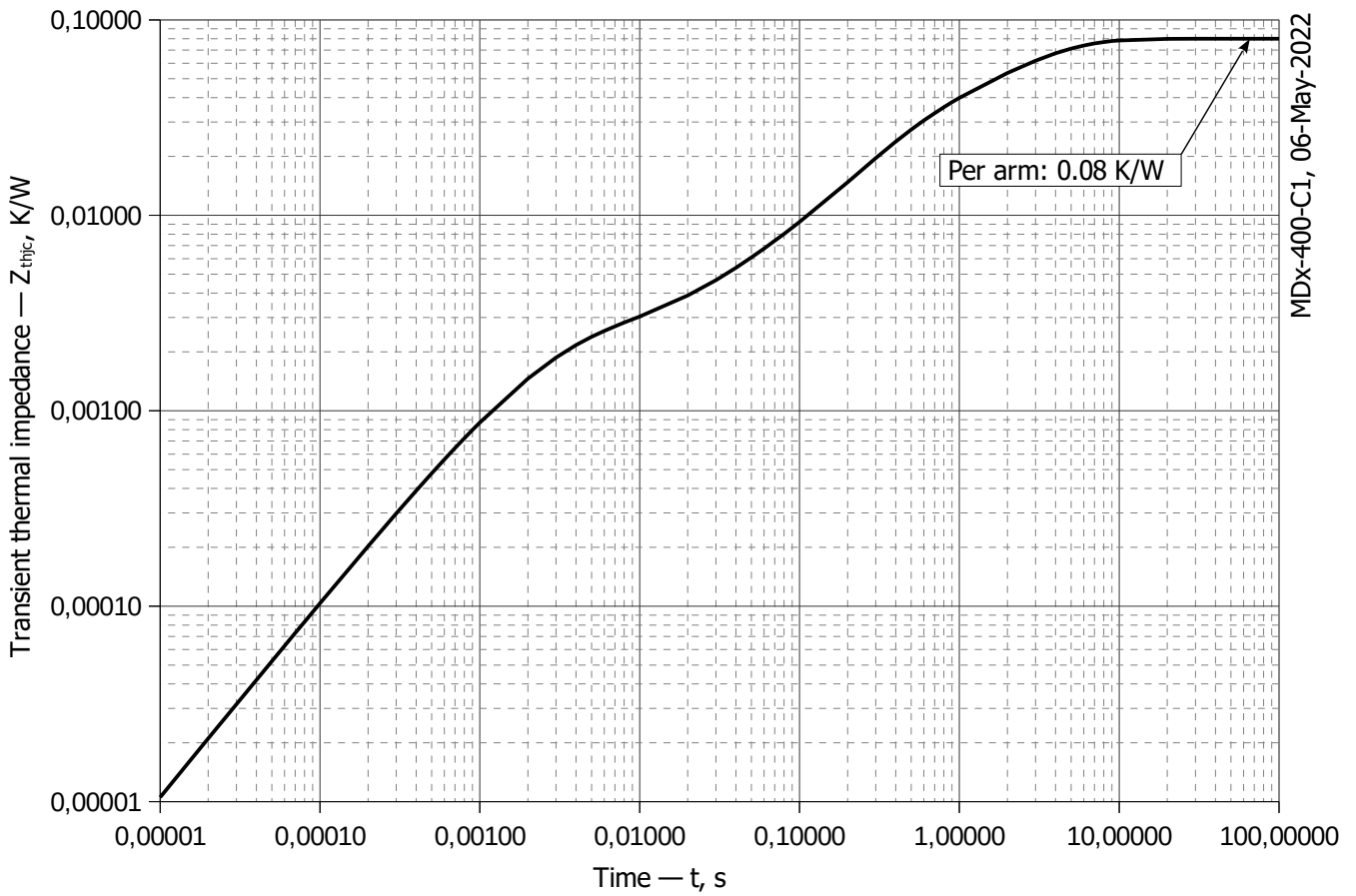


Fig 2 – Transient thermal impedance Z_{thjc} vs. time t

Analytical function for Transient thermal impedance junction to case Z_{thjc} for DC:

$$Z_{thjc} = \sum_{i=1}^n R_i \left(1 - e^{-\frac{t}{\tau_i}} \right)$$

Where $i = 1$ to n , n is the number of terms in the series.

t = Duration of heating pulse in seconds.

Z_{thjc} = Thermal resistance at time t .

R_i = Amplitude of p_{th} term.

τ_i = Time constant of r_{th} term.

DC

| i | 1 | 2 | 3 | 4 | 5 | 6 |
|-------------|--------|----------|---------|-----------|---------|----------|
| $R_i, K/W$ | 0.0507 | 0.007806 | 0.02226 | -0.007688 | 0.00471 | 0.00217 |
| τ_i, s | 2.801 | 1.283 | 0.3281 | 0.09408 | 0.0572 | 0.002255 |

Transient thermal impedance junction to case Z_{thjc} model (see Fig. 2)

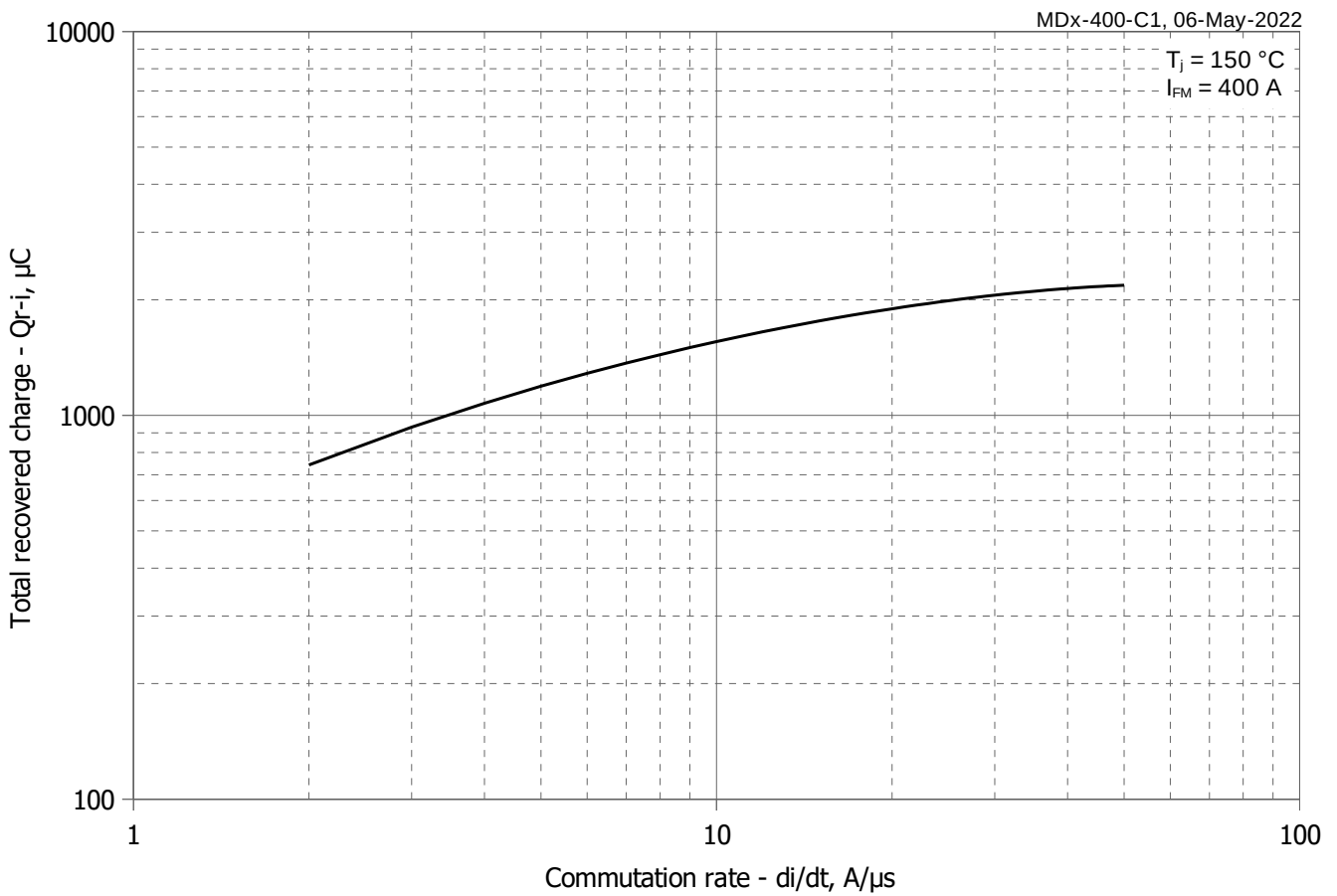


Fig 3 – Maximum recovered charge Q_{r-i} (integral) vs. commutation rate di_R/dt

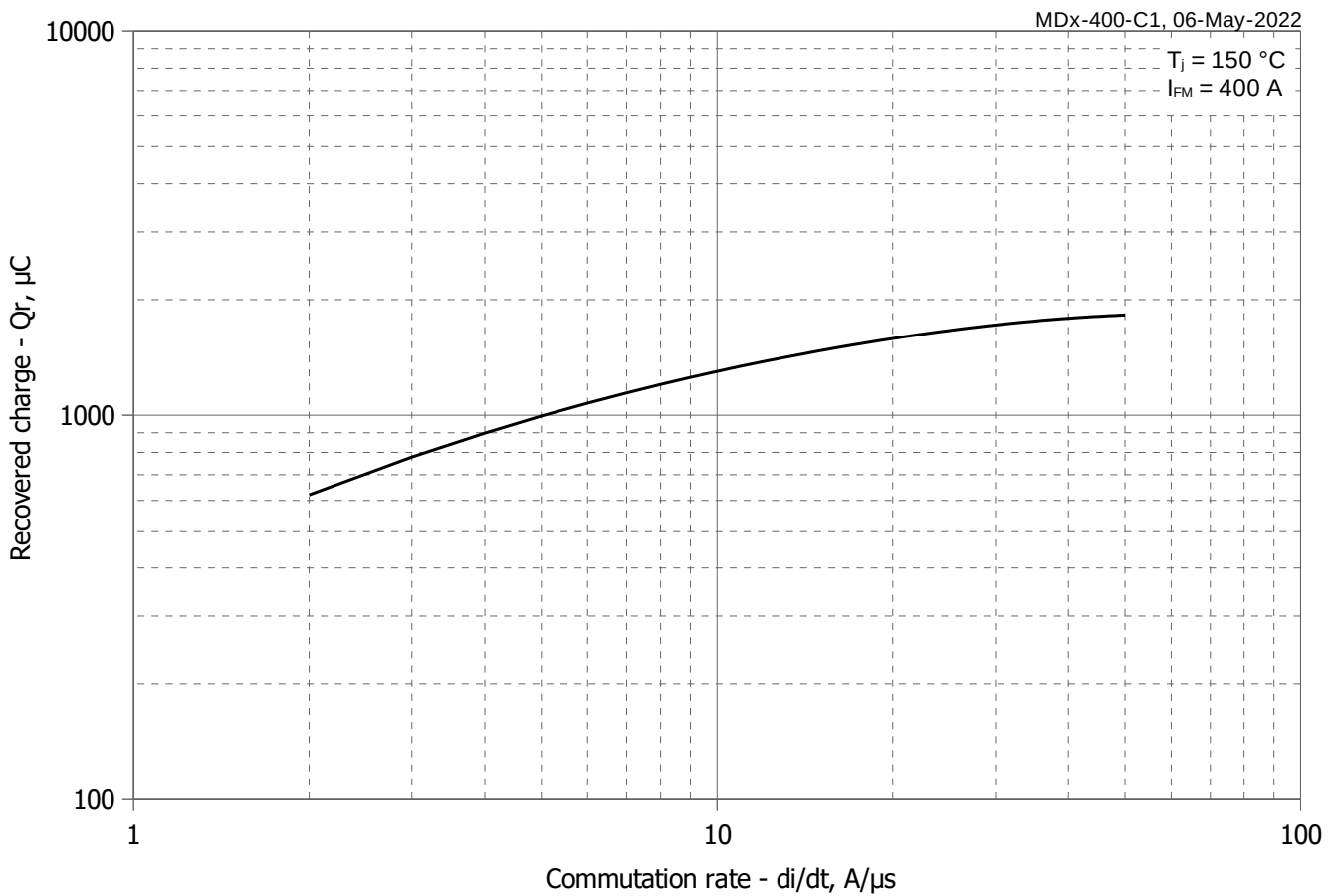


Fig 4 – Maximum recovered charge Q_r vs. commutation rate di_R/dt (25% chord)

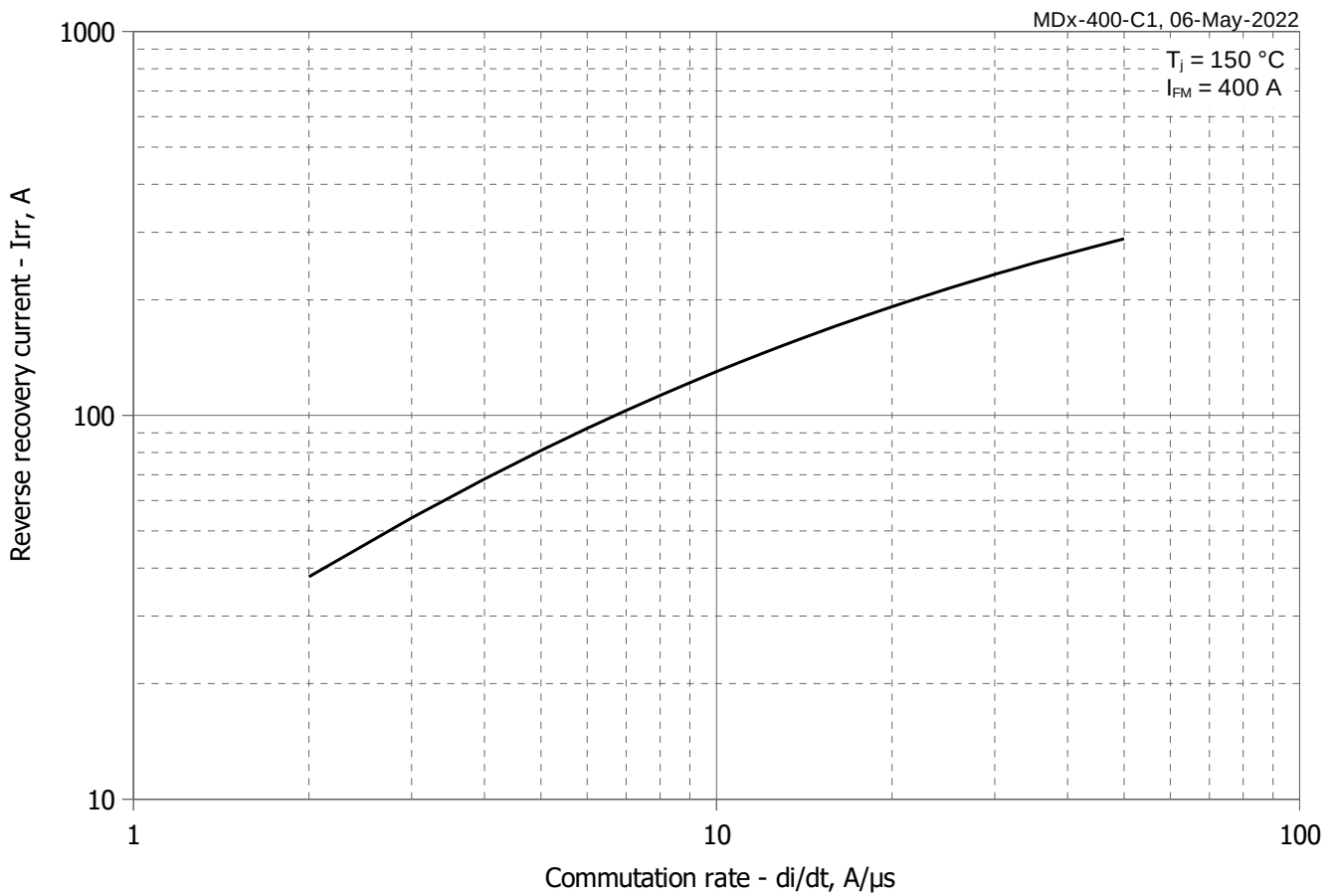


Fig 5 – Maximum reverse recovery current I_{rr} vs. commutation rate di_R/dt

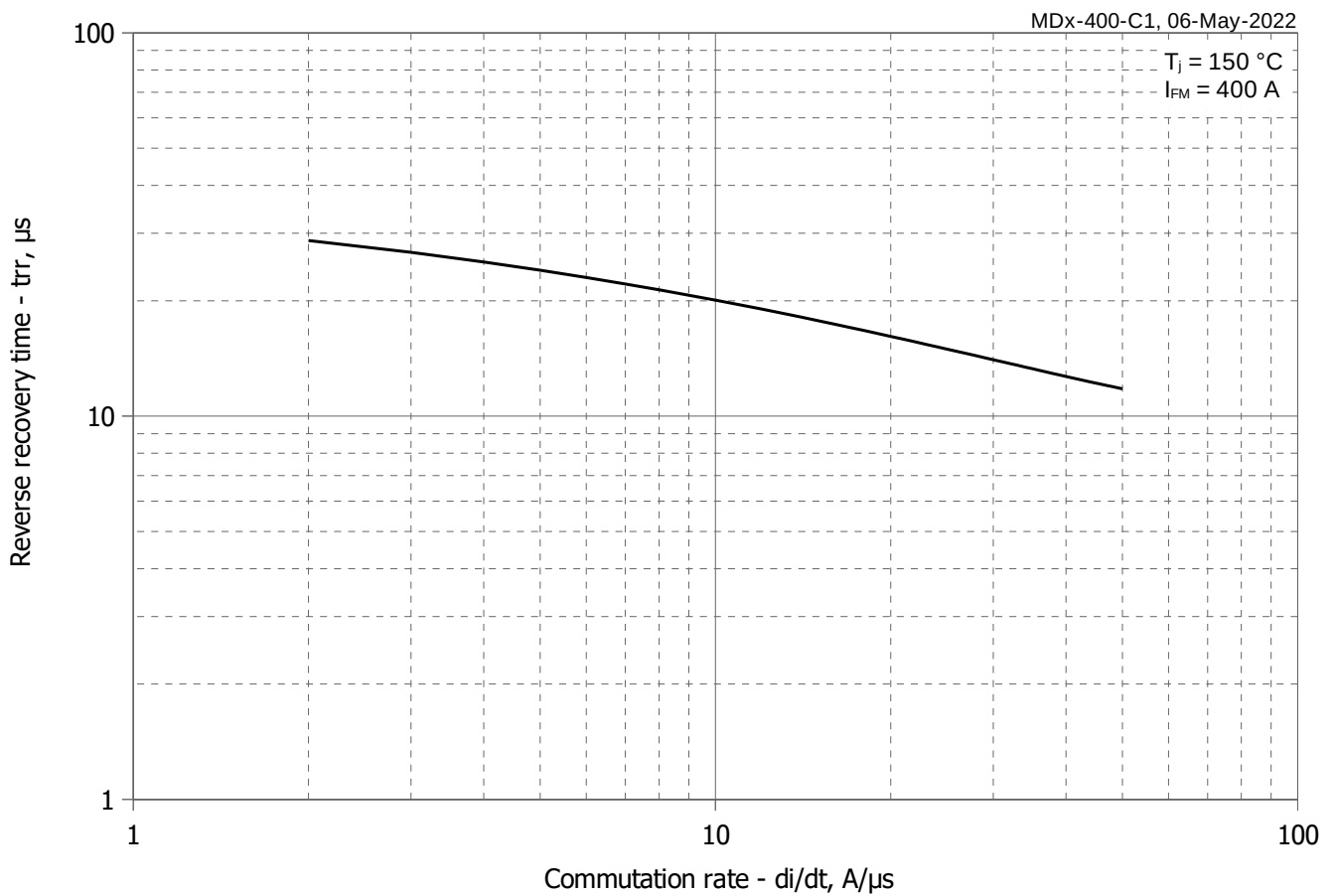


Fig 6 – Maximum recovery time t_{rr} vs. commutation rate di_R/dt (25% chord)

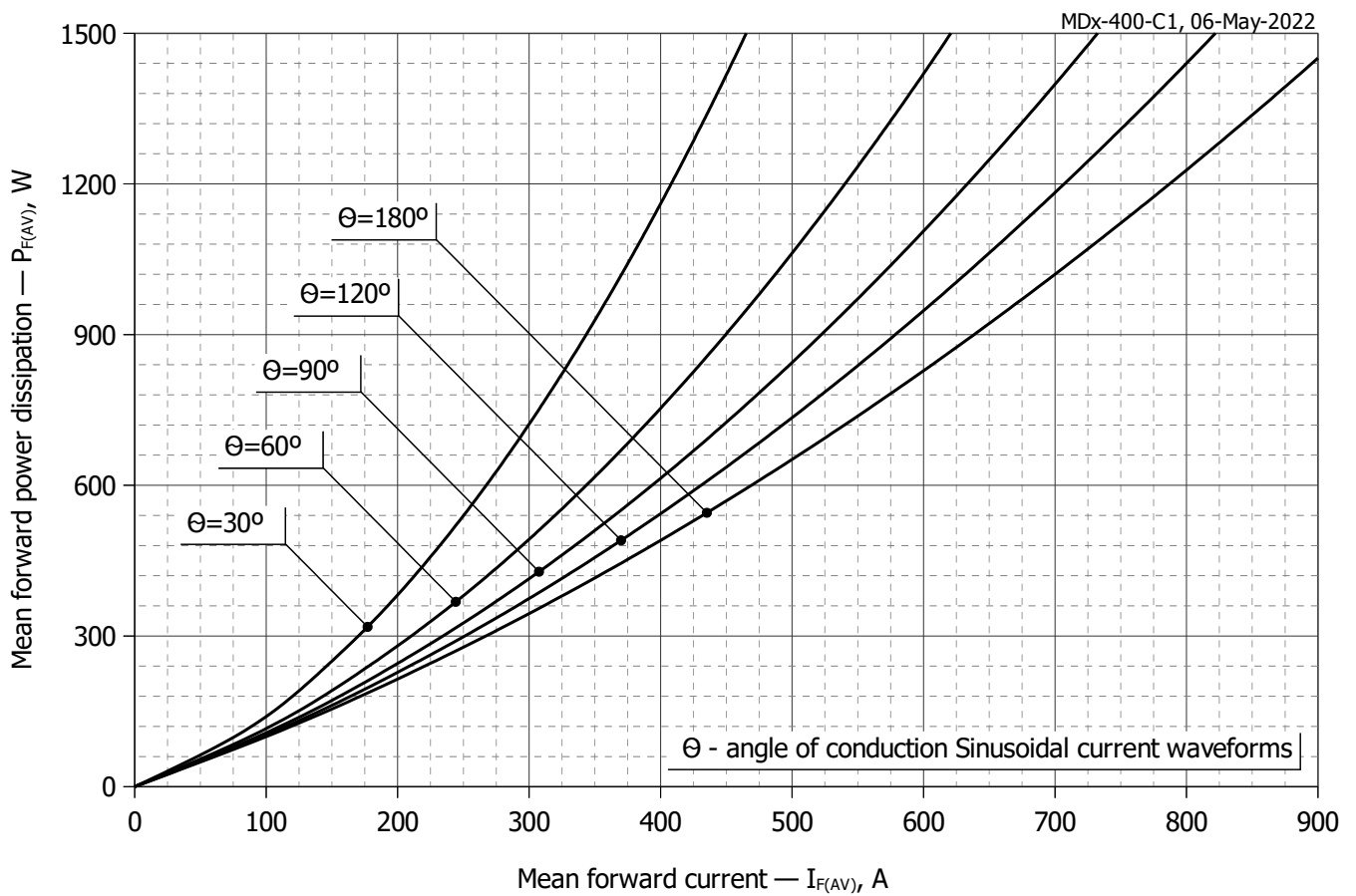


Fig. 7 - Mean forward power dissipation P_{FAV} vs. mean forward current I_{FAV} for sinusoidal current waveforms at different conduction angles ($f=50\text{Hz}$)

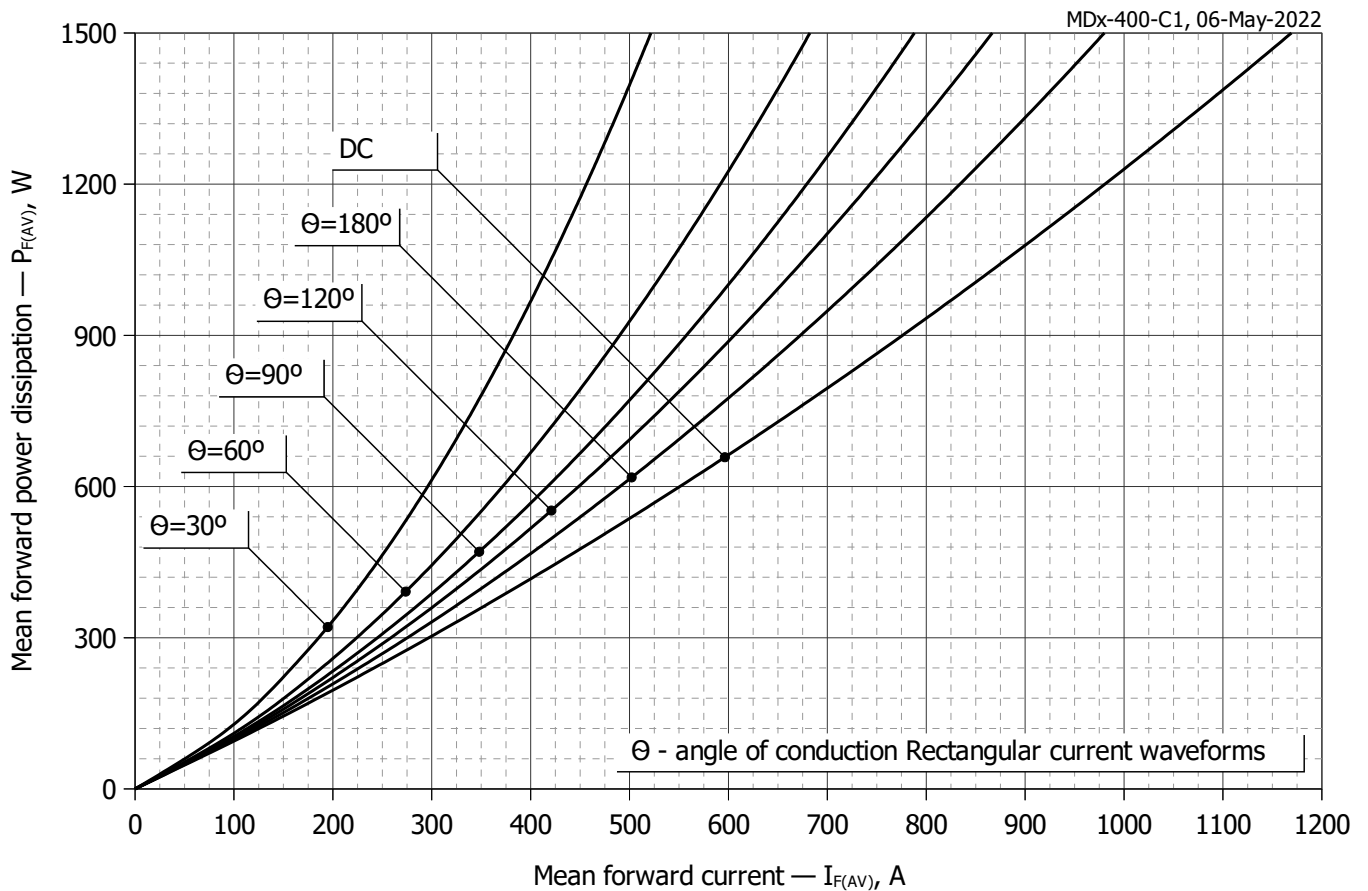


Fig. 8 – Mean forward power dissipation P_{FAV} vs. mean forward current I_{FAV} for rectangular current waveforms at different conduction angles and for DC ($f=50\text{Hz}$)

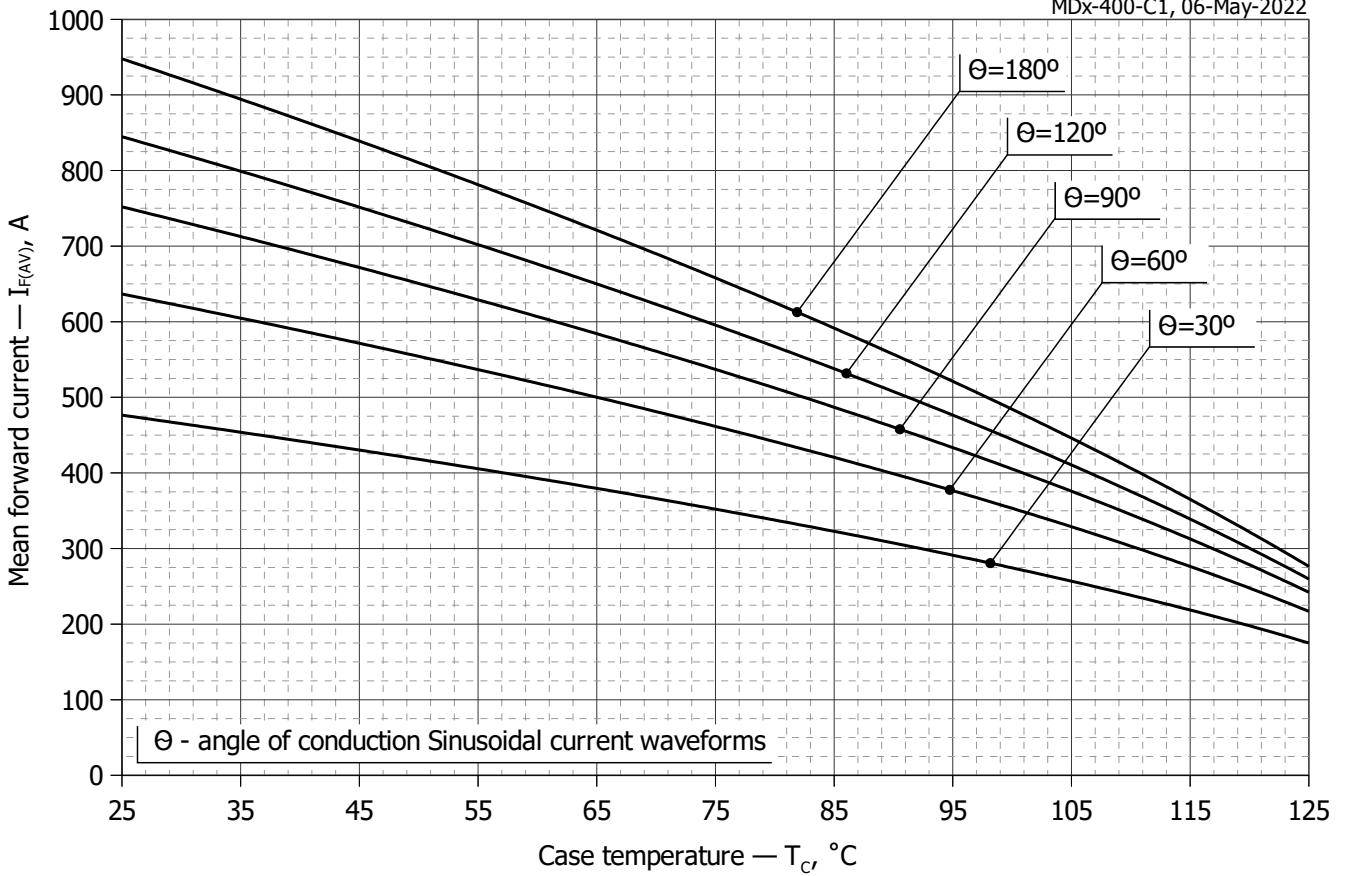


Fig. 9 – Mean forward current I_{FAV} vs. case temperature T_c for sinusoidal current waveforms at different conduction angles ($f=50\text{Hz}$)

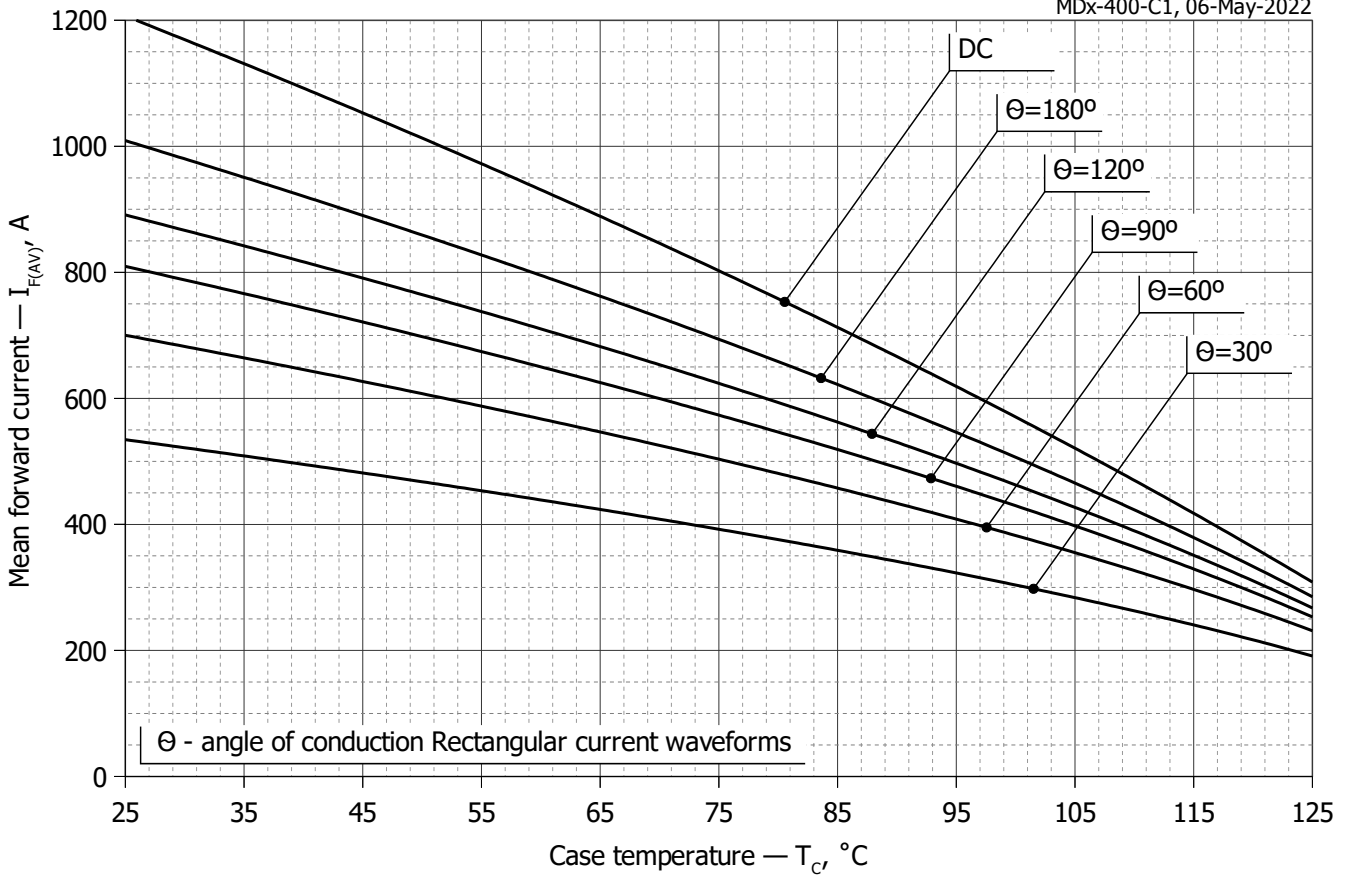


Fig. 10 - Mean forward current I_{FAV} vs. case temperature T_c for rectangular current waveforms at different conduction angles and for DC ($f=50\text{Hz}$)

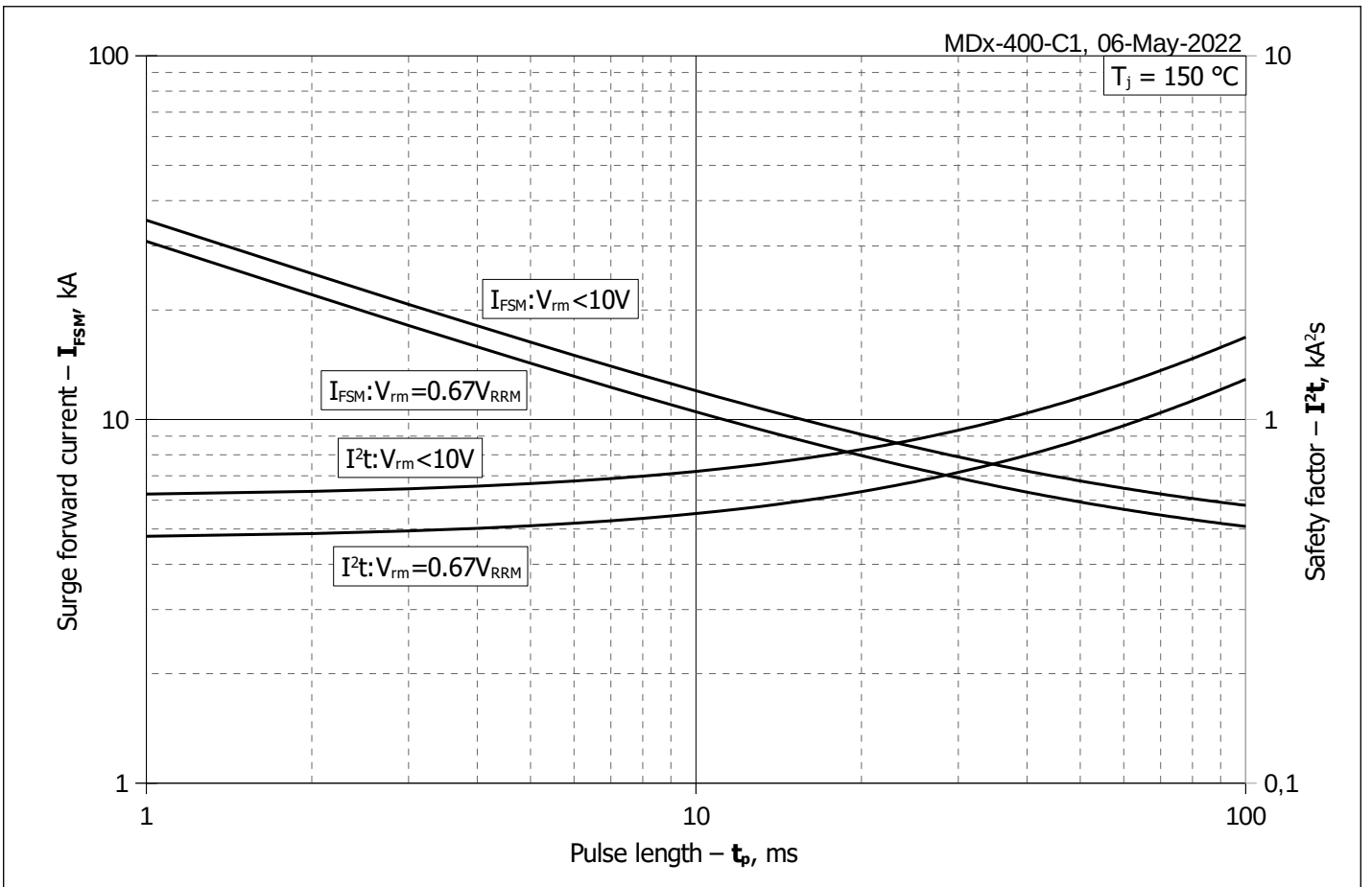


Fig. 11 – Maximum surge forward current I_{FSM} and safety factor I^2t vs. pulse length t_p

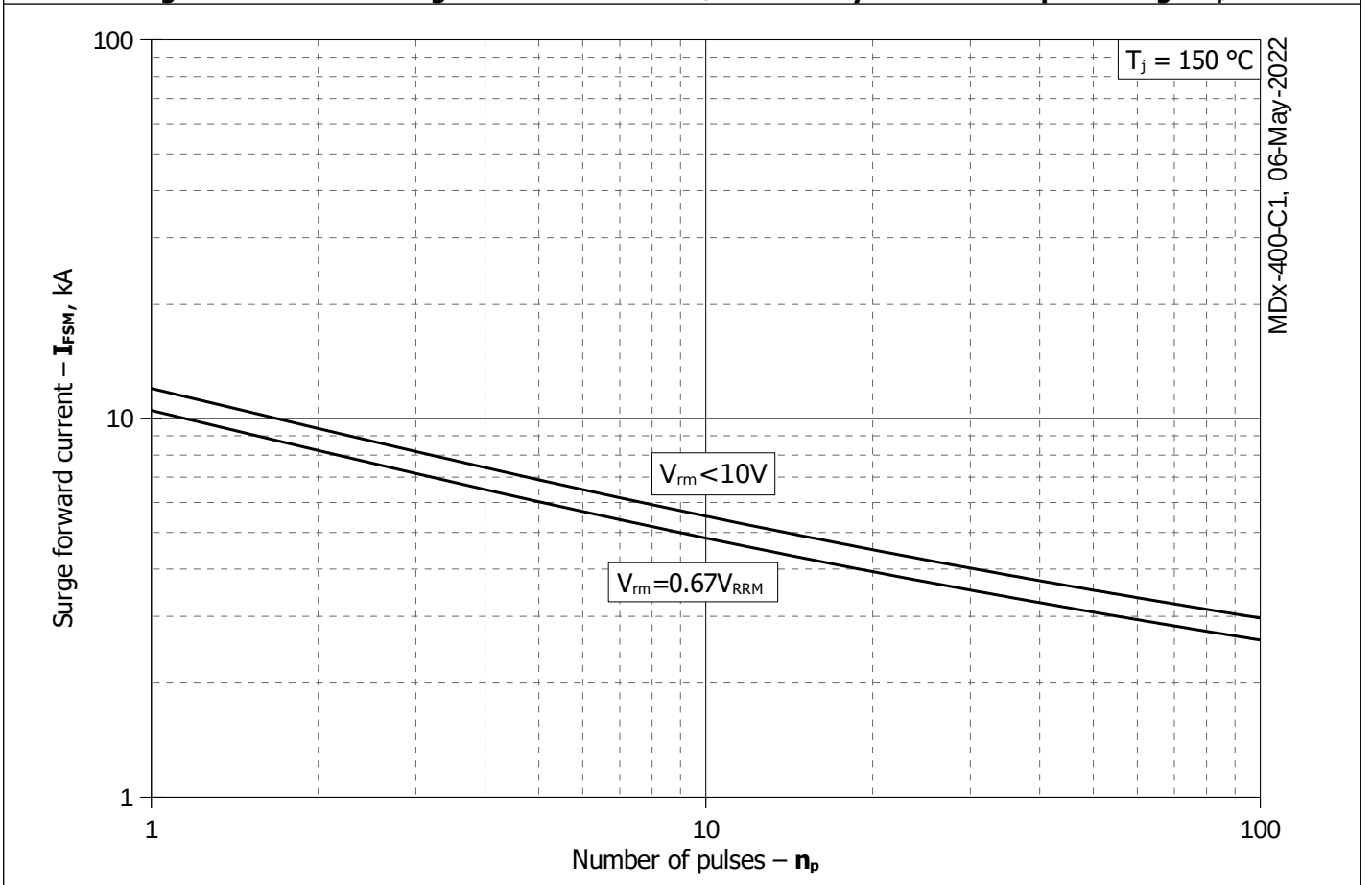


Fig. 12 - Maximum surge forward current I_{FSM} vs. number of pulses n_p